Quantum M onte Carlo simulation for the spin-drag conductance of the H ubbard m odel

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In the situation of two electro-statically coupled conductors a current in one conductor may induce a current in the other one. We will study this phenom enon, called C oulom b drag, in the H ubbard chain where the two \conductors" are given by ferm ions with di erent spin orientation. W ith the aid of a M onte C arlo (M C) approach which we presented in a recent paper we calculate the T ransconductance in di erent variants of the H ubbard chain (with/without impurity and additional [long-ranged] interactions) for di erent llings.

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I. IN TRODUCTION

The Coulomb-drage ect describes how two conductors (only coupled by the Coulom b force) may in uence each other. Since the Coulomb repulsion is relatively small, a sizeable e ect will only arise when the two conductors are very close to each other. This condition can be met in mesoscopic systems where with the advent of new technologies (e.g., carbon nanotubes) the problem of Coulom b drag attracted m ore and m ore attention (e.g., Refs. 1,2,3,4) or in the spin-drag problem. For instead of considering two conductors one may look at drag e ects between di erent ferm ion species, e.g., ferm ions with di erent spin orientation. Since ferm ions with different spins are not spatially separated, there is a large Coulomb force between them which can lead to all kinds of correlation e ects, e.g., a drag e ect. In the last years, the interest in spin-dependent transport increased. One key problem is the generation of a spin-polarized current, i.e., a current where only ferm ions with one of the two spin orientations ow. In this context it is important to keep in m ind that the spin-polarized current m ay a ect the ferm ions with the opposite spin orientation. Hence, the drage ect m ay play here a crucial rôle even though it is experimentally not directly accessible. (This is because the driving potentials are in general not spin dependent.)

For this \spin-drag" problem the trans-resistivity of higher dim ensional system s has been investigated in previous publications, e.g., using the Boltzm ann equation⁵ or the random -phase approxim ation.⁶ In this paper we focus on the Transconductance for the Hubbard model. W hile most authors used a bosonization approach to compute the conductance^{7,8} we will use here, for the study of the Transconductance, a M onte C arlo m ethod which we introduced in a recent paper.⁹ The strategy we followed there was to map our ferm ion system via the Jordan-Wigner transformation to a spin system which can be analyzed by e cient though standard M onte C arlo techniques. W e will now extend this method to the onedim ensional Hubbard model concentrating on the question how a spin-polarized current (driven by a voltage drop which is assumed to be spin dependent) a ects the ferm ions with opposite spin orientation.

In the Section II we present the model and give some central de nitions for the spin-drag problem. The Sec. III contains the technical details on the subject of the M C simulations. The M C method of our choice^{9,10} was a variant of the Stochastic Series Expansion (SSE) as introduced in Refs. 11,12,13,14. This method allows an investigation of the one-dimensional Hubbard model.^{15,16}

In the following Sec. IV A we present our results for the standard Hubbard model and compare with analytical predictions from bosonization theory. To obtain a spin-polarized current we add in Sec. IV B an impurity to the system, which acts like a combination of a onesite chemical potential and a one-site magnetic eld. We show that such a \magnetic" impurity can produce the desired spin-polarized current.

The Hubbard model can also be mapped to a spinlessferm ion ladder. Hence, our results may also describe that situation, but there one might argue that the very speci c modeling of the Coulomb (on-site) interaction in the Hubbard model is unrealistic (and may di er from other approaches, e.g., Refs. 1,2,3,4). We therefore discuss two variants (with additional interaction terms) of ourmodel. First, we will discuss in Sec. IV C a situation, where ferm ions with di erent spins live on di erent sites. The full system has the geom etry of a zig-zag chain. Second, we show in the appendix that a spin-polarized interaction leads to equal C is- and Transconductance. This is sim ilar to the \absolute" drag result found, e.g., in Ref. 3.

II. DEFINITION OF THE SPIN DRAG IN THE HUBBARD MODEL

Our model Hamiltonian is the standard Hubbard model (with N sites or atom s) $% \left({{{\rm{A}}_{\rm{B}}}} \right)$

$$H_{Hubb} = t X X c_{n;}^{y} c_{n+1;} + c_{n+1;}^{y} c_{n;}$$

$$n_{X} = ";# X n_{n;} + U n_{n;"} n_{n;#}; (1)$$

$$n_{i} n_{i} n_{i} n_{i}$$

where n_n ; is the occupation number of fermions with spin at site n, and $c_n^{(y)}$ is the corresponding annihilation (creation) operator. To perform our transport calculations, we will use the approach from Ref. 9. Since the hopping term does not connect fermions with di erent spins, it is natural to consider current and potential operators for each spin orientation separately. Following Ref. 9 the potential operators read then: (e being the charge unit and x being the position of the voltage drop)

$$P_{x}^{\#} = e_{n_{n;\#}}^{X} P_{x}^{\#} = e_{n_{n;\#}}^{X} n_{n;\#};$$

The conductance (of a spinless-ferm ion chain) is the linear response of one potential operator to another; therefore the explicit form of the current operators is not needed here.⁹ A swe have two potentials, we can de ne four transport quantities (conductances) g_{ij} which describe the (linear) response of Pⁱ to P^j where i; j 2 f";# g. Further details on how to evaluate the g_{ij} 's are to be found in section III.

For the m on ent we will discuss only sym m etric m odels, i.e., we have spin-rotational invariance (the only asym – m etric m odel that we will discuss appears in Sec. IV B); thus, we end up with only two distinct quantities. We call $g_c \coloneqq g_{\#\#} = g_{\#}$ the C isconductance and $g_t \coloneqq g_{\#} = g_{\#}$ the Transconductance.

The naming conventions come from the physical interpretation of these coe cients which is the following: If we switch on at a certain time a (supposedly) spin-polarized potential which acts only on spin-up fermions (i.e., we add a time-dependent perturbation of the form

VP" (t)

with V being the voltage am plitude and the H eavysidestep function) we will nd a current of spin-up ferm ions

$$I'' = g_c V$$
:

T his is the drive current governed by the C isconductance, but there will also be a current of spin-down ferm ions

$$I^{\#} = g_{t}V;$$

the drag current (governed by the Transconductance). The latter m ay be nonzero, even though the spin-down ferm ions do not feel the applied potential.

The situation of a nonvanishing Transconductance (or drag current) is called C oulom b drag. This problem has been studied, e.g., for coupled spinless-ferm ion systems by bosonization in Refs. 1,2,3 and to second-order perturbation theory in Ref. 4.

Normally, (since spin-polarized potentials are not available) one is only interested in the (full) conductance of the Hubbard model, where both ferm ion species feel the same potential, and the full current is the sum of the currents of the spin-up and spin-down ferm ions. As is straightforward to see, the C is- and T ransconductance give us directly the conductance of the Hubbard model via the relation $g_{\rm Hubbard} = 2 (g_{\rm c} + g_{\rm t})$.

III. DESCRIPTION OF THE MONTE CARLO METHOD

Before starting with M onte Carlo we have to cast our H am iltonian in a convenient form .

Using the Jordan-W igner transform the Hubbard model can be mapped to a spin ladder. To each occupation operator we introduce a spin operator, i.e., we replace $n_{n,i}$! $S_{2n}^{z} + 1=2$ and $n_{n,i}$! $S_{2n+1}^{z} + 1=2$. If we express the Hubbard H am iltonian with those new operators we obtain the following spin ladder (with 2N sites):

$$H = X_{x} (S_{n}^{+}S_{n+2} + S_{n}S_{n+2}^{+}) = 2 + J_{z}S_{n}^{z}S_{n+1}^{z} + BS_{n}^{z}$$

+
$$US_{2n}^{z}S_{2n+1}^{z} + U^{0}S_{2n+1}^{z}S_{2n+2}^{z}; \qquad (2)$$

where the sites with even number represent spin-up ferm ions and the sites with odd numbers, spin-down ferm ions. (For the Hubbard model one has to put $J_z = 0 = U^0$. These parameters are used to model the spin-polarized interaction from the appendix and the zigzag chain from Sec. IV C; see bottom half of Fig. 1. The sites 2n and 2n + 1 in the ladder represent therefore one atom of the Hubbard model and interact via an Ising interaction representing the Coulomb force (see Fig. 1). The hopping am plitudes satisfy $J_x = 2t$, and the strength of the magnetic eld B in Eq. (2) is obtained from the chem ical potential via the relation $B = U = 2 + U^{0} = 2$ Half lling corresponds therefore to B = 0. The two potential operators P_v^{",#} introduced in the previous section can be related to potential operators for the two chains (e being the charge unit)

$$P_{x}^{\#} = e_{n > x}^{X} S_{2n+1}^{z}; P_{x}^{"} = e_{n > x}^{X} S_{2n}^{z}:$$

Then we may obtain the four conductances g_{ij} introduced in the previous section by computing $(i; j 2 \ f\#; "g)$

$$g_{ij}(!_{M}) = !_{M} = \cos(!_{M}) P_{x}^{i} P_{y}^{j}(i) id$$
 (3)

at the M atsubara frequencies $!_{M} = 2 \text{ M} (\sim)^{-1}$; M 2 N, and then extrapolating to ! = 0. (The extrapolated value should not depend on x or y.⁹ We chose x = N = 2 = y = 1.) For the extrapolation from $g(!_{M})$ to g(! = 0) we will use a quadratic t from the rst three M atsubara frequencies. [W e will use open (OBC's) instead of periodic boundary conditions (PBC's).] Since the H am iltonian contains H eisenberg-like interactions as well as Ising-like interactions, it is advantageous to use the Stochastic C luster Series Expansion (SCSE) introduced in Ref. 10. For the H ubbard m odel the SCSE gives essentially the same update scheme as the one used in Ref. 16. W e will explain it now shortly.

Follow ing R ef. 10 we split the H am iltonian according to H = $h_{2h}h$, but this time into four-sites clusters, called

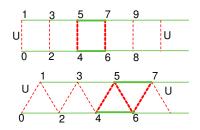


FIG.1: The model H am iltonian that will be discussed in this paper. Solid lines indicate a full H eisenberg-like interaction between the sites; dashed lines stand for sites coupled only by a z-z term (Ising-like interaction). The upper part is for $U^0 = 0$. The lower for $U^0 = U$. (O ther values of U^0 are not considered.) A plaquette as used in the MC scheme is indicated by boldface lines.

plaquettes (see Fig. 1). The following operators belong to the plaquette P (containing interactions between the sites 2n, 2n + 1, 2n + 2, and 2n + 3):

$$\begin{split} h_p^{(1)} &= J_x S_{2n}^+ S_{2n+2} = 2 & h_p^{(2)} = J_x S_{2n} S_{2n+2}^+ = 2 \\ h_p^{(3)} &= J_x S_{2n+1}^+ S_{2n+3} = 2 & h_p^{(4)} = J_x S_{2n+1} S_{2n+3}^+ = 2 \\ h_p^{(5)} &= C + U = 2 S_{2n}^z S_{2n+1}^z + U = 2 S_{2n+2}^z S_{2n+3}^z + \\ &+ U^0 S_{2n+1}^z S_{2n+2}^z + J_z S_{2n+1}^z S_{2n+3}^z + J_z S_{2n}^z S_{2n+2}^z \\ &+ B = 2 (S_{2n}^z + S_{2n+1}^z + S_{2n+2}^z + S_{2n+3}^z) : \end{split}$$

The set h consists of all $h_p^{(t)}$ for all plaquettes P and all $t = 1; \dots; 5$.

The heart of the SC SE program is the so called bop update, where a spin ip of a subset (bop) of all spin variables is proposed. Since the sites with even and odd numbers form two chains, which are only coupled by a z-z interaction term, we nd that the set of spin variables that will be ipped in the bop update belongs entirely to one of the chains. Therefore, we can view the new algorithm as making bop updates for each chain separately. D uring a bop update for one chain the spin variables of the other chain remain xed. The consequence of this is that, if we update, e.g., the even chain, then operators with superscript i = 3;4 can be neglected (are irrelevant for the loop construction), and the coupling terms (between the chains) reduce to magnetic eld term s (for the even chain).

It is however advantageous to consider another variant of the loop update. The construction is similar to the rst variant, but now we propose spin ips for both chains, i.e., the spin variables belonging to sites 2n and 2n + 1 are ipped simultaneously. This may be viewed as a construction of two parallel loops one for each chain. Since the two loops must be parallel, the num ber of possible transitions between di erent plaquette states is reduced. This may lead to a less e cient algorithm, ¹³ but one should note that this parallel-loop update becomes determ inistic for the case of B = 0 and hence enhances the e ciency of the algorithm (at least for this situation) considerably.

IV. NUMERICALRESULTS A. Transconductance in the Hubbard model

1. C om parison with the Hubbard model

In bosonization theory the H ubbard m odel is described by two boson elds ";# representing the degrees of freedom of di erent spin orientations. The current operators for the spin sectors are then given by $J_{";#} / \mathfrak{e}_{x}$ ";#.⁷ The conductance can be written in the form of a currentcurrent correlator⁷ and m ay be evaluated in term s of the Luttinger-liquid parameters K; of the charge and spin eld = (" #) = 2. The result is (using the linearity of the correlator and the results from Ref. 17)

$$g_c = \frac{1}{2} (K + K)$$
 $g_t = \frac{1}{2} (K - K)$: (4)

W hen = U=2 we are at half lling, where Um klapp processes are responsible for a gap in the system $.^{18}$ The (charge) gap (U) depends on the Hubbard repulsion U and is nite for all U.

2. Num erical sim ulations

W e present now M onte C arlo results for the Transconductance in the Hubbard model Eq. (1) [or Eq. (2) for $U^0 = 0$].

We perform ed simulations for two dierent chemical potentials: First, = U=2 corresponding to half lling and second = 0. In the latter case the system is no longer at half lling, but has a U-dependent lling, which is shown in Fig. 11 of the appendix (in the large-U lim it the system reaches quarter lling).

We show g_c and g_t as a function of U for the two different 's in Fig.2. The gure shows that the Coulomb drag is very sensitive to a change in chem ical potential.

Let us rst look at the half-lled case (Fig. 2). If U is very large the Coulomb repulsion acts as an e ective projection to those con quantions satisfying $P^{\#} = P^{"}$. This implies that $g_c + g_t ! 0$ as U ! 1. This contemplation is in accordance with Fig. 2. We should actually expect from Eq. (4) that for T = 0 we have $g_c + g_t = K = 0$ because of the charge gap (U) > 0 for allU > 0 (cf.Ref. 18). This should lead to a discontinuous jum p at U = 0, because without the C oulom b force evidently $g_t = 0$ and g_c is the conductance of uncoupled spinless-ferm ion chains from Ref. 17. Here we em phasize that our method is a nite-tem perature method, which means that the conductances calculated by us interpolate sm oothly between the values for U = 0 and U = 1. The crossover is expected to take place at that interaction value U_T which satis es $(U_T) = k_B T$. It is therefore interesting to see how $g_{c;t}$ scale with tem perature. However, our method gives only access to the

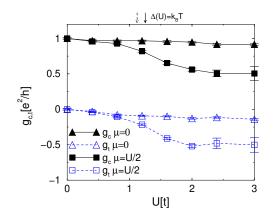


FIG. 2: C is- and Transconductance (lled/em pty symbols) of the Hubbard model as a function of U for two di erent 's (200 sites, T = $0.02t=k_B$, OBC's, 2 10^5 MC sweeps.) The (solid) arrow indicates the U_T for which the charge gap (present at half lling) satis es (U _T) = k_B T. (The dotted arrow show sU_{T=2} where (U _{T=2}) = k_B T=2 for com parison.)

low-T regime,⁹ such that we will compare here results for only two di erent tem peratures, $k_{\rm B} T = 0.01t$ and $k_{\rm B} T = 0.02t$. In the two subsequent simulations for the Cis-/Transconductance we did not nd any di erence at all. This im plies only a weak tem perature dependence (at low T) for the interaction U_T which governs the crossover. Since (U) is known from analytical results,¹⁹ we can calculate the two crossover interactions de ned $(U_{0:02}) = 0:02t$ and $(U_{0:01}) = 0:01t$ nding that by $1:25t \text{ and } U_{0:01}$ 1:12t do not di ermuch, as $U_{0:02}$ expected (they are also both indicated by arrows in Fig. 2).

A nother in portant consequence of $g_c + g_t ! 0$ is that the signs of the C is- and T ransconductance are opposite or | in term softhe spin-up and spin-down currents| that the induced drag current ows in the opposite direction of the drive current.²⁰

Now we will turn to the spin sector. We have K = 1 by spin-rotational invariance of the Hubbard model¹⁸ in plying [see Eq. (4)] g_c $g_t = 1$ for all U which is very well satis ed by Fig. 2.

Putting the two results for $g_c = g_t$ together, we obtain $g_c = 0.5e^2 = h = g_t$ valid at high U. This large-U limit of q m ay also be computed in second-order perturbation theory. In this approximation the Hubbard model can be mapped to a Heisenberg model. The operator [on the Hilbert space of the original Ham iltonian Eq. (1)] P_x , which is e ectively equal to $P_x^{\#}$, is identified with the operator (on the Hilbert space of the e ective Heisenberg $n > x T_n^z$. $[T_n^z = (n_n; n_n; \#)=2$ is the m odel) $P_x =$ spin operator for ferm ions; here denoted by T to avoid confusion with the spin operators appearing in Sec. III.] Applying the results from Ref. 9 the computation of g_c reduces then to the computation of the spin conductance of the Heisenberg model, which equals one half in units $e^2 = h$.

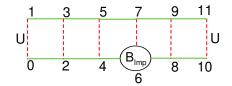


FIG.3: Them odelH am illonian with an impurity at site N = 2 for N = 6 in the spin ladder representation from the upper half of Fig.1 (for U⁰ = 0). The site on which the impurity potential acts is encircled.

In the case of zero (again Fig.2) where the system is away from half lling there is no charge gap. Hence, K is nite, and so Eq. (4) tells us that $g_t + g_t = K$ does not decay with U. [Here we note that $g_c + g_t$ agrees (within error bars) with the values for K available in Ref. 18.] We still have K = 1, which leads to $g_c = g_t = 1$ for all U (again very well satis ed by the gure).

Finally, we consider the large-U limit. Inserting K (U = 1) = 0.5 and K 1 from Ref. 18 in Eq. (4) yields $g_c = 0.75$ and $g_t = 0.25$ (units $e^2=h$). These results are in accordance with the gure. (Note that the statistical error increases with U such that we cannot compute g(U) for su ciently high U in order to extract the large-U limit accurately.)

B. M agnetic Im purity

In this subsection we will study the in uence of an impurity. The modeling of the impurity follows Ref. 7, but for the spin-drag problem it is natural to consider a spin-dependent impurity, as we will do here. We extend therefore our H am iltonian in the following way

$$H = H_{H ubb} + B_{Im p} n_{N = 2;"};$$

i.e., we introduce an (impurity) potential at exactly one central site (which acts only on one spin orientation, see Fig. 3).

Fig. 4 shows C is conductances and Transconductances as a function of the in purity potential B $_{\rm Im \, p}$ at half lling. (The example is chosen such that the Transconductance in the unperturbed system is relatively large.) The conductance of the H eisenberg chain with one in purity, which is the large-U lim it of g_c, is given for com parison.

A lthough the two C isconductances, $g_{""}$ and $g_{\#\#}$, could in principle di er (the model is now asymmetric) they do not in the case of half lling | at least within error bars. Both C isconductance and Transconductance go | more or less linearly | to zero as the impurity strength increases.

W e note that within error bars $g_c = g_t$ such that the full conductance of the system

$$g = 2(g_c + g_t)$$

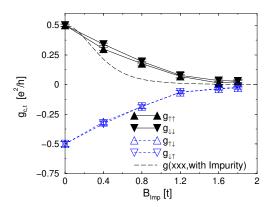


FIG. 4: The C is- and Transconductance (lled/em pty symbols) as a function of the impurity strength B $_{\rm Im\,p}$ at half lling. The impurity acts on spin-up ferm ions. Note that the C isconductance for the spin-up ferm ions g_{**} (triangle up) m ight di er from the one of the spin-down ferm ions $g_{\#\#}$ (triangle down). The two Transconductances are the same. The conductance of an xxx (H eisenberg) chain with one impurity (which should coincide with the large-U lim it of the C isconductance) is given for comparison. (= U=2, U = 2t, N = 192 sites, T = 0:02t=k_B .)

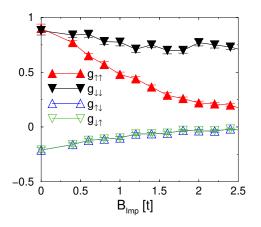


FIG.5: The C is- and Transconductance (lled/em pty symbols) as a function of the impurity strength B $_{\rm Im\,p}$ in the Hubbard model away from half lling. The impurity acts on spin-up ferm ions. Note that the C isconductance for the spin-up ferm ions g_{**} (triangle up) di ers from the one of the spin-down ferm ions $g_{#\#}$ (triangle down). The two Transconductances are the same. (= 0, U = 4t, N = 192 sites, T = 0.02t=k_B.)

remains zero after insertion of the impurity. Furthermore, investigations with our method at dierent temperatures nd no sizeable T-dependence.

In the case of zero chem ical potential, = 0, we da splitting of the two C isconductances (see Fig. 5). This is particularly interesting since this ding implies a spin-polarized current. If we assume a (spin-independent) driving potential of the form

(V being the voltage am plitude), then the current is

$$I = I'' + I^{\#};$$
 $I'' = (g_{""} + g_{"\#})V$ $I^{\#} = (g_{\#"} + g_{\#\#})V;$

The average spin of a ferm ion in the current is therefore (using $g_{\#^{\, u}} = \, g_{u^{\, } \#} = \, g_t)$

$$S = \frac{I'' I^{\#}}{2I} = \frac{g_{""} g_{\#\#}}{2(g_{""} + g_{\#\#} + 2g_{L})}$$

di erent from zero (see Fig. 6).

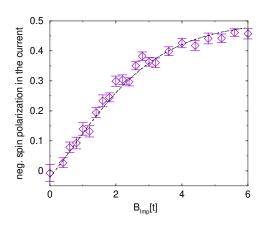


FIG.6: The negative average spin polarization (S) of the induced current as a function of the impurity strength B $_{\rm Im\,p}$ in the Hubbard model away from half lling. The impurity acts on spin-up fermions. The dashed curve is obtained by tting g**, g** and gt in Fig.5 with an exponential ansatz and substituting these ts into the form ula for S. (= 0, U = 4t, N = 192 sites, T = 0.02t=k_{\rm B}.)

An interesting problem is the question whether for = 0 the C isconductance in the pure (spin-down) sector $g_{\#\#}$ survives or not when we increase B Im p to in nity. Note that a nite $q_{\#}$ would imply a total spin polarization, i.e., S = 1=2. The lim it $B_{Imp} ! 1$ of $g_{\#}$ cannot be taken directly (because of problem s with the M C simulation), but here we note that there is another way to model the impurity. Instead of applying a local magnetic eld on one site, one can introduce a weak link, i.e., decrease the hopping am plitude for spin-up ferm ions between the sites N = 2 and N = 2+1 from the initial value t to t_{Imp} . These two variants of in purities behave sim ilarly.⁷ We computed the Cisconductance for the una ected spin orientation for the model with $t_{Im p} = 0$ (corresponds to $B_{Imp} = 1$) at = 0, U = 4t, N = 200 sites. We nd a value of about $[0:79 \quad 0:03]e^2=h$.

The di erent behavior of the C isconductance in the (una ected) spin-down sector at half lling and away from half lling may be explained as follows: Suppose $B_{Im\,p}$ and U are large. The e ect of the $B_{Im\,p}$ term on the ferm ions is that it forbids occupation of the impurity site for one of the two ferm ion species (in our case spin-up ferm ions). At half lling a spin-up ferm ion can hop only from one site to another by exchanging the site with a spin-down ferm ion (there are no empty sites),

i.e., simultaneously with the spin-up a spin-down ferm ion must hop in the opposite direction et vice versa (im plying $g_c = g_t$). A ferm ion of a certain spin index can then only pass the impurity site if accompanied by a ferm ion of opposite spin (which moves in the opposite direction). Since the impurity site is forbidden for one of the two ferm ion species, no ferm ion can pass the impurity site, and both C isconductances must go to zero.

Away from half lling the hopping of an spin-up ferm ion does not necessarily require the hopping of a spin-down ferm ion (the spin-up ferm ion can hop to an empty site) and hence the impurity a ects only one of the two C isconductances.

C. Zig-zag chain

So far we have dealt with a system of two fermion species, where the two species reside on the same set of sites. In contrast to this, the bosonization approaches considered mostly systems of two coupled spinless-ferm ion conductors. W e can com pare our results with that situation, if we interpret the Hubbard model as a spinless-ferm ion ladder. Here one assum es that each ferm ion species lives on a di erent conductor [i.e., the two indices (n;") and (n;#) are supposed to label (spatially) di erent sites; com pare Sec. III and upper half of Fig. 1]. But one should note that for this case the parameter U should be small (since the distance between separated conductors is large) and the Coulom b interaction should be long-ranged (not on-site as in the Hubbard model). Hence we are led to the question how a variation in the interaction term modi es our results.

To address this question we add a new interaction term to the Hubbard model

$$H = H_{Hubb} + U n_{n;\#}n_{n+1;"}$$
:

This Ham iltonian corresponds to Eq. (2) with U⁰ = U. One can justify introducing this new interaction term if the ferm ion species live on di erent sites where each spindown site (n;#) lies between two spin-up sites, (n;") and (n + 1;"). This model has therefore the geometry of a frustrated zig-zag chain as depicted in the lower half of Fig. 1.

O ne should note that this system has a total of 2N sites, N sites for each ferm ion species. A though it would be useful to adopt the notion of a system with two coupled (spinless-ferm ion) chains, we will keep here the notation of a system of spinfull ferm ions.]

The results for the spin drag in this model are shown in Fig. 7. We discuss again two chem ical potentials: one is = U in plying half lling, the other is again = 0. In the latter case the (m ean) occupation number per site n is di erent from one half (the occupation at half lling) and depends on U. It is shown in Fig. 8.

O ne sees in Fig. 7 that $j_{c,t}$ j grow with the strength of the interaction. This may be explained as follows: First,

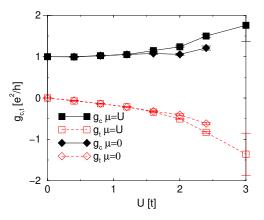


FIG.7:C is-and Transconductance (lled/em pty symbols) of the zig-zag chain for two m agnetic elds (120 sites per ferm ion species, T = 0:02t=k_B, U⁰ = U in Eq. (2), OBC's, 2 10^5 MC sweeps.)

the C oulom b interaction m ediates an attractive nearestneighbor interaction for ferm ions with equal spin orientation (this is a consequence of the frustration). Therefore, in a simple approximation the only e ect of the C oulom b interaction is to renormalize the Luttinger-liquid param – eters for the two spin sectors K ";[#]. Since the Luttinger parameter for a spinless-ferm ion chain increases with the strength of the attraction,⁸ we expect that K ";[#] increases as U increases. Since K ";[#] gives the conductance of one spin sector¹⁷ (which is essentially the C isconductance) we have that g_c increases with U.

O nem ay also infer from the gure that the dependence $ofg_{c;t}$ on a chem ical-potential shift is weak. W ithin error bars g_c decreases only slightly upon shifting away from half lling.

O ne should note that in the lim it U = 1 the ground state is a spin-polarized con guration (see Fig. 9). For = U this means that all conductances are zero in the large-U lim it, for one spin sector is empty and the other, completely lled. In contrast to this, for = 0 one of the two spin sectors may remain conducting. The crossover to the ordered state occurs at values of U larger than 3t which may be seen by simulating and comparing the occupation number for di erent states. For = 0 the di erenge in occupation (between the two spin sectors) $n = hj_n (n_{n;"} n_{n;\#}) j = (2N)$ is shown in Fig. 8; for = U it is zero within error bars as long as U 3t. W e conclude that for the values of U considered in Fig. 7 the two spin sectors have approximately the same lling.

V. CONCLUSION

In this paper we discussed the spin drag for the Hubbard model at zero temperature. We found that the Transconductance is negative | at half lling the Um k-lapp even enforces $g_c = g_t$. In that respect our situation is di erent from two coupled Tom onaga-Luttinger mod-

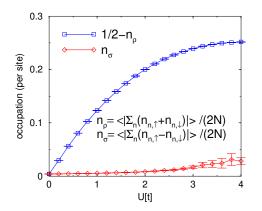


FIG. 8: O ccupation per site (n) and di erence between the occupations of the two ferm ion species (n) for the zig-zag chain. (100 sites per ferm ion species, PBC's, $= 0, 10^4$ MC sweeps, T = 0:1t.)

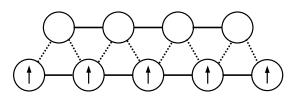


FIG. 9: One of two possible ground state con gurations for the zig-zag H am iltonian when U >> t. The sites in the lower row are occupied by spin-up fermions, the sites in the upper row are empty. In the other ground state, the lower row is empty, and the upper completely led with (spin-down) fermions.

els as considered in Refs. 1,2,3 which do not incorporate Um klapp. The \absolute-drag" result of the form $g_c = g_t$ (e.g., from Ref. 3) can only be recovered by introducing a spin-polarized interaction (see appendix).

If we assume that a given potential is in general not spin dependent, the only relevant quantity is the full conductance $g = 2(g_c + g_t)$, which is only nonzero away from half lling. Here both spin orientations contribute equally to the current. However, the situation changes when we add a magnetic impurity. Even if the driving potential is still spin independent, the resulting current will be (partially) spin polarized, if we are away from half lling. In the lim it of a large impurity potential the current will be fully spin polarized.

APPENDIX A:SPIN-DEPENDENT INTERACTION | BROKEN SPIN-ROTATIONAL INVARIANCE

In the Hubbard modelC is-and Transconductance have opposite sign, in sharp contrast to the bosonization results (for coupled spinless-ferm ion chains), where C isand Transcoductance are both positive. The discrepancy may come from the di erent modeling of the interaction. In the bosonization approaches each chain is given by an interacting system (i.e, the Luttinger-liquid param eter K m ay di er from one), in the H ubbard m odeleach spin sector alone is represented by a noninteracting ferm ion system . W e will show in this appendix that a spin-polarized interaction leads to a positive T ransconductance as found in the bosonization approaches. To this end w e w ill now discuss the follow ing variant of our H am iltonian:

$$H = H_{Hubb} + J_{z} (n_{n}; 1=2) (n_{n+1}; 1=2): (A1)$$

Here the new J_z term breaks the spin-rotational invariance. Hence K may now be di erent from one.

First we consider the large-U lim it at half lling. The U term acts then as an e ective projection to the con gurations with exactly (because of half lling) one ferm ion per site, i.e., $n_{n;r} = 1$ $n_{n;\#}$. We now set-up an effective (second-order perturbation theory) H am iltonian. From the kinetic-energy term we get again a H eisenberg m odel with exchange parameter $4t^2$ =U. The J_z term of the H am iltonian does not change the con guration (in the occupation-num ber basis) and gives therefore a direct energy contribution $2J_z \ n T_n^z T_{n+1}^z$ to the e ective H am iltonian where $T_n^z = (n_{n;r} \ n_{n;\#})=2$ denotes the spin of the ferm ion on site n. The fulle ective H am iltonian reads

$$H_{e} = \begin{array}{c} X \\ (4t^{2}=U) (T_{n}^{+} T_{n+1} + T_{n+1}^{+} T_{n}) = 2 \\ + \begin{array}{c} X^{n} \\ (2J_{z} + 4t^{2}=U) T_{n}^{z} T_{n+1}^{z}; \end{array}$$

and is an xxz chain. If the anisotropy is larger than the hopping am plitude, i.e., if $J_z > 0$, this model is gapped (im plying both a charge and a spin gap in the original model). We therefore expect that C is-and Transconductance go to zero, if we increase U and keep a nite J_z .

Now we consider a zero chem ical potential = 0. We expect that this chem ical potential shift away from half

lling closes the charge gap, but leaves the spin gap m ore or less una ected. We consider again the large-U lim it. In any con guration the J term of the H am iltonian gives the following contribution for two neighboring sites

- $J_z=2$ if the two sites are occupied with anti-parallel spins,
- $J_z=2$ if the two sites are occupied with parallel spins or are both empty,
 - 0 if one site is occupied and the other, not.

W e assume that there is a spin gap and that the (degenerate) ground state con gurations are those for which the spins of the particles are ordered antiferrom agnetically. If only these con gurations are allowed, the J term can be represented as a one-site potential with a contribution

 $J_z=2$ for empty/occupied sites. (O ne obtains the same energy contributions as from the J_z term of the original H am iltonian, if one keeps in m ind that each site appears in precisely two pairs of neighboring sites.) We can setup the following e ective H am iltonian (this is just the

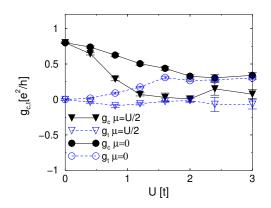


FIG.10: The same as Fig.2, but for J_z = 0.8t (here N = 140). The simulations away from half lling su er from large autocorrelation times.

restriction of the original H am iltonian to the assumed ground state con gurations, i.e., zeroth order in U)

X
[(
$$R_n^+ R_{n+1}^- + R_{n+1}^+ R_n^-$$
)=2+ J_z R_n^z];

which is an xx chain in magnetic eld, where the \spin" operator R_n^z (this time denoted by R to avoid confusion with previous spin operators) is de ned by R_n^z = 1=2 if there is a particle on site n and R_n^z = +1=2 if site n is empty. Since the e ective Ham iltonian describes the charge part of the Ham iltonian the full conductance 2 (g_c + g_t) for the originalm odel should coincide with the conductance of the new Ham iltonian which is e²=h as the system is noninteracting.^{8,17} Since we have g_c = g_t by the assumption of a spin gap and Eq. (4), the relation $g = 2 (g_c + g_t)$ yields $g_c = 0.25 e^2 = h = g_t$.

In principle the model Eq. (A1) can also be analyzed with the M onte C arb method developed in this paper, but we found that the simulation for this case is problem – atic: W e measured large autocorrelation times for nite J_z and (e.g., for the computation of the compressibility). We therefore must restrict ourselves to J_z 0.8t.

For $J_z = 0.8t$ we present results for the C is- and

Transconductance in Fig. 10. In the large-U limit we nd good agreement with our prediction that $g = g_t = 0.25 e^2$ =h which gives credit to the simulation data despite the large autocorrelation times.

Here we want to stress once again the remarkable fact that the sign of the Transconductance (the direction of the induced current) changes when we switch the magnetic eld and the spin-polarized interaction on. (The Transconductance is for all U negative in Fig. 2 whereas in the present situation we expect g_t = g_c = K =2 > 0 for T = 0;U = 1 .)

O ccupation in the ground state | Since we identied the ground state of the H am iltonian Eq. (A1) H (= 0;U! 1) with the ground state of the xx chain in magnetic

eld, we can calculate the occupation per state of this Ham iltonian in the large U -lim it, the result being:

$$(n_n;)=N = 1 \ arccos(J_z=[2t])= :$$

This prediction may be tested against a Monte Carlo simulation. We nd good agreem ent (see Fig. 11).

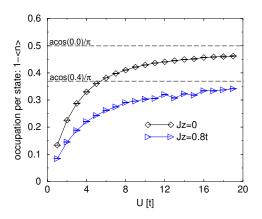


FIG.11: Occupation per state (away from half lling) for the Hamiltonian Eq. (A1) H (= 0) for dierent J_z. The predicted high U values are given as dashed lines. (500 sites, PBC's, 10^5 MC sweeps, T = 0.1t.)

- ¹ K.Flensberg, Phys.Rev.Lett. 81 184 (1998).
- ² A.Komnik R.Egger, EPJ condm at/0007443
- ³ Yu D. Nazarov and D. Averin, Phys. Rev. Lett. 81, 653 (1998).
- ⁴ N A .M ortensen, K .F lensberg, and A P. Jauho, Phys. Rev. Lett. 86, 1841 (2001); Phys. Rev. B 65 085317 (2002).
- ⁵ K. Flensberg, T.S. Jensen, and N.A. Mortensen, Phys. Rev.B 64, 245308 (2001).
- ⁶ I. d'Am ico and G. Vignale, Phys. Rev. B 68, 045307 (2003); ibidem 62, 4853 (2000); Y. Takahashi, K. Shizum e, and N. Masuhara, Physica E 10, 22 (2001).
- ⁷ C L.K ane and M PA.Fisher, Phys.Rev.Lett. 68, 1220 (1992); Phys.Rev.B 46, 15233 (1992).
- ⁸ A.Gogolin, A.Nersesyan, and A.Tsvelik, Bosonization

and Strongly Correlated System s, Camebridge University Press, Camebridge 1998.

- ⁹ K.Louis and C.Gros, Phys. Rev. B 68, 184424 (2003).
- ¹⁰ K.Louis and C.G ros, submitted to Phys.Rev.B condm at/0310465.
- ¹¹ A.Domeich and M.Troyer, Phys.Rev.E 64, 066701 (2001).
- ¹² A W . Sandvik and J. Kurkiarvi, Phys. Rev. B 43, 5950 (1991); A W . Sandvik, J. Phys. A 25, 3667 (1992).
- ¹³ O F. Syljasen and A W. Sandvik, Phys. Rev. E 66, 046701 (2002).
- ¹⁴ A W . Sandvik, \Stochastic series expansion m ethod with operator-loop update", Phys. Rev. B 59, R14157 (1999).
- ¹⁵ R.T.Clay, A.W. Sandvik, and D.K.Campbell, Phys.Rev.

B 59,4665 (1999).

- ¹⁶ P. Sengupta, A.W. Sandvik, and D.K. Campbell, Phys. Rev.B 65, 155113 (2002).
- ¹⁷ W . Apeland T M . Rice, Phys. Rev. B 26, 7063 (1982).
- ¹⁸ H.J.Schulz, Phys. Rev. Lett. 64 2831 (1990); \The M etal-Insulator Transition in One D in ension" at Los A lam os

M eeting on strongly correlated E lectron system s, D ec 1993, cond-m at/9412036.

- ¹⁹ Y. Um eno, M. Shiroishi, and A. K lum per, Europhys. Lett.
 62 284 (2003).
- ²⁰ P.Schlottm ann, Phys. Rev. B 69, 035110 (2004).